



CHENMKO ENTERPRISE CO.,LTD

GLASS PASSIVATED

HIGH EFFICIENCY RECTIFIER

VOLTAGE RANGE 50 - 1000 Volts CURRENT 5.0 Amperes

HER501GPT

THRU

HER508GPT

Lead free devices

FEATURES

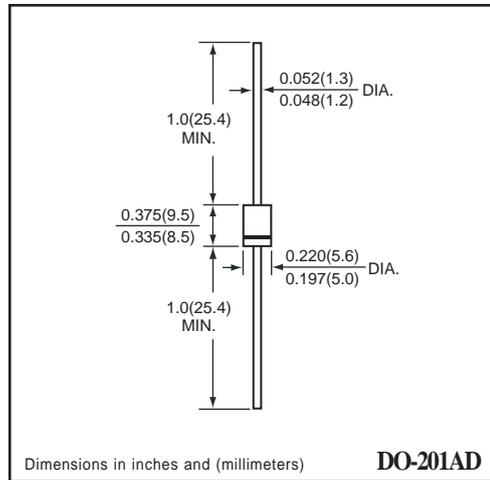
- * Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- * Low power loss, high efficiency
- * Low leakage
- * High current capability
- * High speed switching
- * High current surge
- * High reliability
- * Glass passivated junction
- * High temperature soldering guaranteed : 260°C/10 seconds at terminals

MECHANICAL DATA

Case: JEDEC DO-201AD molded plastic
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity: Indicated by cathode band
Weight: 1.20 grams



DO-201AD



DO-201AD

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	HER501GPT	HER502GPT	HER503GPT	HER504GPT	HER505GPT	HER506GPT	HER507GPT	HER508GPT	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	300	400	600	800	1000	Volts
Maximum RMS Voltage	VRMS	35	70	140	210	280	420	560	700	Volts
Maximum DC Blocking Voltage	Vdc	50	100	200	300	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at TA = 50°C	Io	5.0								Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	IFSM	250								Amps
Typical Junction Capacitance (Note 1)	CJ	70				50				pF
Operating and Storage Temperature Range	TJ, TSTG	-65 to +175								°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

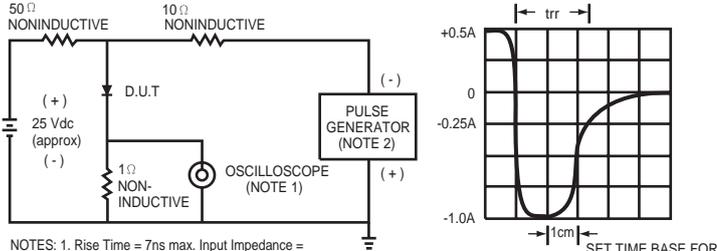
CHARACTERISTICS	SYMBOL	HER501GPT	HER502GPT	HER503GPT	HER504GPT	HER505GPT	HER506GPT	HER507GPT	HER508GPT	UNITS
Maximum Instantaneous Forward Voltage at 5.0 A DC	VF	1.0		1.3		1.70				Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage at TA = 25°C	IR	10								uAmps
Maximum Full Load Reverse Current Average, Full Cycle 0.375" (9.5mm) lead length at TL = 55°C		150								uAmps
Maximum Reverse Recovery Time (Note 2)	trr	50				70				nSec

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 4.0 volts
 2. Test Conditions : IF = 0.5 A, IR = -1.0 A, IRR = -0.25 A

2001-6

RATING CHARACTERISTIC CURVES (HER501GPT THRU HER508GPT)

FIG. 1 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. Rise Time = 7ns max. Input Impedance = 1 megohm. 22pF.
2. Rise Time = 10ns max. Source Impedance = 50 ohms.

FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

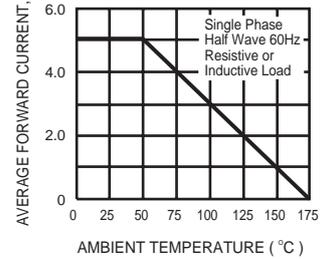


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

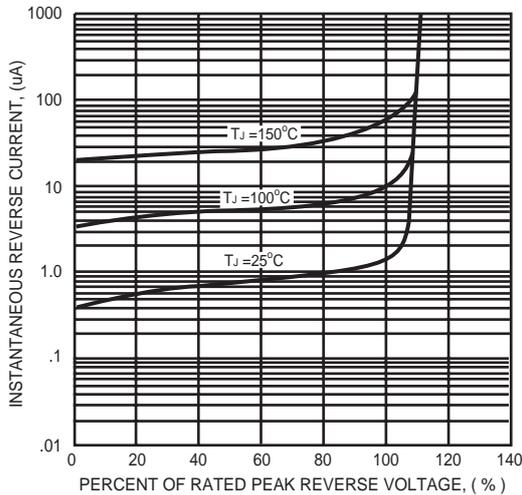


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

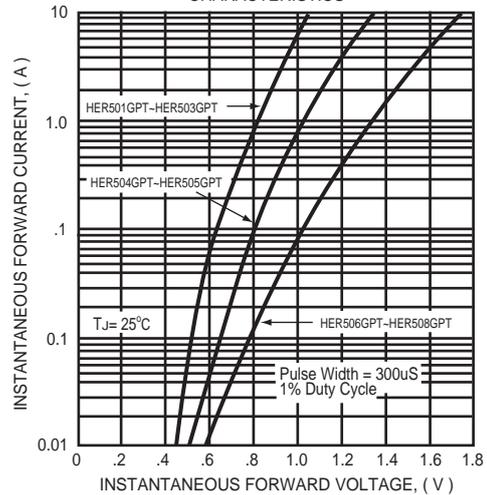


FIG. 5 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

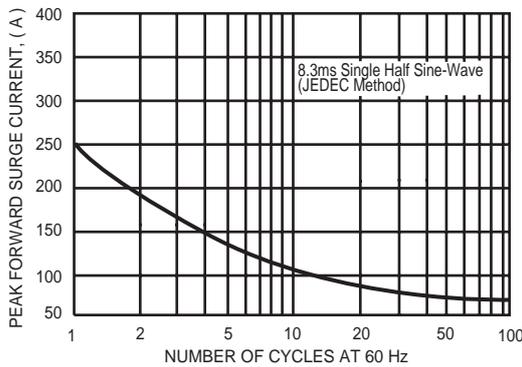


FIG. 6 - TYPICAL JUNCTION CAPACITANCE

